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Contribution to the theory of valve photoeffect...

is maintained in the n-region. 4. The thickness of the n-region is small. Certain results of this work can be used in determining the dark current-voltage characteristics of p-n junctions with inhomogeneous p- and n-regions. There are 8 figures.

ASSOCIATION: Institut poluprovodnikov Akademii Nauk SSSR Leningrad (The Institute of Semiconductors, Academy of Sciences USSR, Leningrad)

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